High-pressure lattice dynamical study of bulk and nanocrystalline In$_2$O$_3$


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The effect of pressure on the vibrational properties of bulk and nanocrystalline powders of cubic bixbyite-type In$_2$O$_3$ has been investigated at room temperature by means of Raman spectroscopy up to 31.6 and 30 GPa, respectively. We have been able to follow the pressure dependence of up to sixteen and seven Raman modes in bulk and nanocrystalline cubic In$_2$O$_3$, respectively. The experimental frequencies and pressure coefficients of the Raman-active modes of bulk cubic In$_2$O$_3$ at ambient pressure are in good agreement with those predicted by our theoretical ab initio calculations. Furthermore, a comparison of our experimental data with our calculations for the Raman modes in rhombohedral corundum and orthorhombic Rh$_2$O$_3$-II structures and with already reported Raman modes of rhombohedral corundum-type In$_2$O$_3$ at room pressure indicate that Raman scattering measurements provide no experimental evidence of the cubic to rhombohedral or cubic to orthorhombic phase transitions either in bulk material or in nanocrystals up to 30 GPa.

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I. INTRODUCTION

Indium oxide (In$_2$O$_3$) is an attractive semiconductor material that it is employed as a transparent conductive oxide in many industrial applications, because of its wide direct (3.75 eV) and indirect (3.10 eV) band-gaps with additional high charge-carrier mobility. Due to these characteristics, In$_2$O$_3$ has been used in several applications like the production of solar cells, light-emitting diodes, liquid-crystal displays, and gas sensors. The improvement in performance of those applications and the development of new applications can also be envisaged in nanomaterials with controlled size and shape. In this context, significant research efforts have been made for successful preparation of size-controlled In$_2$O$_3$ nanocrystals, hereafter named nano In$_2$O$_3$.

At ambient conditions, In$_2$O$_3$ crystallizes in the cubic bixbyite-type structure (space group (SG) $Ia\bar{3}$, No. 206, $Z = 1$), which is common to most rare-earth sesquioxides. However, several high-pressure phases are reported for this compound, like the rhombohedral corundum-type structure (SG $R\bar{3}c$, No. 167, $Z = 6$), the orthorhombic Rho$_2$O$_3$-II structure (SG $Pbnm$, No. 60, $Z = 4$), and the orthorhombic $\alpha$-Gd$_2$S$_3$ structure (SG $Pnma$, No. 62, $Z = 4$). In the cubic, rhombohedral, and Rho$_2$O$_3$-II structures, cations are sixfold-coordinated; however, cation coordination increases to seven and eight in the $\alpha$-Gd$_2$S$_3$ structure. In recent years, the rhombohedral corundum-type structure of In$_2$O$_3$ has been synthesized at ambient conditions in a metastable way in different nanostructures and thin films. In particular, the corundum phase is expected to show better properties than the bixbyite phase, like better stability and more conductivity, therefore, it is of great interest to study the various pressure-induced phases of In$_2$O$_3$.

The properties of bulk bixbyite-type In$_2$O$_3$ have been thoroughly investigated at ambient conditions. In particular, its vibrational properties in bulk as well as in thin films have been studied since the 1970s. More recently, corundum-type In$_2$O$_3$ has been reported and characterized at ambient conditions by Raman spectroscopy, evidencing the differences between the Raman-active modes of the cubic and rhombohedral phases. On the other hand, the properties of In$_2$O$_3$ nanocrystals are receiving increasing attention in the last years, and recently, the vibrational properties of In$_2$O$_3$ nanostructures have started to be also investigated.

As regards the studies of bulk cubic In$_2$O$_3$ under pressure, it has been reported that cubic In$_2$O$_3$ retains its cubic structure till 6 GPa and 1450°C; on the other hand, it has been reported that In$_2$O$_3$ subjected to pressures of 6.5 GPa and temperatures between 880 and 1300°C result in the growth of rhombohedral In$_2$O$_3$ when retrieved at ambient conditions. The rhombohedral phase of In$_2$O$_3$ has also
been found by applying shock waves in the pressure range of 15–25 GPa to cubic In$_2$O$_3$. More recently, Yusa et al. observed by X-ray diffraction (XRD) measurements the R$_h$$_2$O$_3$-II phase as post-corundum phase in In$_2$O$_3$ at 7 GPa and 1900 K and the x-Gd$_2$S$_3$ phase as post-Rh$_2$O$_3$-II phase above 40 GPa and 2000 K. Finally, Liu et al. carried out both powder XRD and Raman spectroscopy studies up to 27.8 and 26.2 GPa, respectively. They have shown that the compound remains stable up to 15.3 GPa, when it undergoes a phase transition to the corundum structure. On the other hand, In$_2$O$_3$ nanocrystals have been less studied under pressure than bulk In$_2$O$_3$. In particular, Qi et al. performed powder XRD measurements up to 40 GPa at room temperature in In$_2$O$_3$ nanocrystals with average size of 6 nm. They showed that cubic In$_2$O$_3$ nanocrystals remain stable to 23.6 GPa, pressure at which they undergo a phase transition to the corundum structure.

In this paper, we report Raman scattering measurements of bulk and nanocrystalline powders of cubic In$_2$O$_3$ at ambient temperature. Unlike previous works that report the existence of six Raman-active modes out of the twenty-two expected ones, we show up sixteen (seven) Raman-active modes of the cubic phase in bulk (nano) In$_2$O$_3$. Additionally, we report the pressure dependence of the Raman-active mode frequencies of the cubic phase in bulk (nano) In$_2$O$_3$. The Raman-active modes of the cubic phase are in good agreement with our lattice-dynamics calculations in the bulk material. We will show that our Raman scattering measurements do not provide clear evidence of the cubic to rhombohedral or cubic to orthorhombic phase transitions either in bulk material or in nanocrystals up to 30 GPa.

II. EXPERIMENTAL DETAILS

Commercial indium oxide powder (99.99% pure) from Sigma-Aldrich Inc. and as-grown nanocrystals of In$_2$O$_3$ were used in this work. The nanocrystals of In$_2$O$_3$ were prepared by nonhydrolytic alcoholysis ester elimination reaction of indium acetate in a procedure similar to that reported earlier. Starting reagents for the preparation were indium acetate, oleyl alcohol, oleic acid, and methanol. About 0.5 mg of indium acetate along with 40 ml oleyl alcohol and 2.5 ml of oleic acid were taken in a 100 ml volume three-necked flask. The reaction flask was evacuated to a vacuum level of 2 mbar and heated slowly to 100 °C and held for 1 h. After the evacuation, the vacuum was cut off and slowly argon was introduced to the reaction flask. The reaction system was heated to 220 °C under flowing argon atmosphere and maintained at this temperature for 4 h. The reaction solution was then cooled to 60 °C, and excess of methanol (40 ml) was added to precipitate the nanocrystals. The precipitate was separated by centrifugation.

In$_2$O$_3$ nanocrystalline powder was characterized at ambient pressure by powder XRD collected on a Panalytical X-pert pro diffractometer using CuK$_\alpha$ radiation (Figure 1). All the observed reflections can be attributed to cubic-In$_2$O$_3$ with a unit cell parameter $a = 10.1214(8)$ Å and volume $V = 1036.9(2)$ Å$^3$. The obtained unit cell parameter and volume are in agreement with those reported earlier in the literature. The size of crystallites of nano In$_2$O$_3$ was obtained from the full width at half maximum (FWHM) of the (222) Bragg peak using the Scherrer relation with a shape factor of 0.9. The average crystallite size of the nanocrystals is about 9 ± 3 nm.

Raman scattering measurements were performed at room temperature in a backscattering geometry using the 632.8 nm laser line and a Horiba Jobin-Yvon LabRam HR UV spectrometer in combination with a thermoelectrically cooled multichannel CCD detector with a resolution below 2 cm$^{-1}$. High-pressure Raman measurements in bulk and nanocrystalline powders of In$_2$O$_3$ up to 31.6 and 30 GPa, respectively, were performed in a membrane-type DAC using a 50× large working distance objective and laser power below 10 mW. We used a mixture of methanol-ethanol-water in the proportion 16:3:1 as a quasihydrostatic pressure-transmitting medium and a few ruby balls of about 2 µm in diameter evenly distributed in the pressure chamber as a pressure sensor. The pressure was determined using the ruby fluorescence scale. The experimental phonons have been analyzed by fitting, when possible, Raman peaks with a Voigt profile (Lorentzian convoluted with a Gaussian) where the Gaussian linewidth (1.5 cm$^{-1}$) is used to describe the electronic and dynamical properties. The description of the exchange-correlation energy was described with the generalized gradient approximation (GGA) with the PBEsol prescription. A dense special k-points sampling for the Brillouin Zone (BZ) integration...
was performed in order to obtain very well converged energies and forces. At each selected volume, the structures were fully relaxed to their equilibrium configuration through the calculation of the forces and the stress tensor. It allows to obtain the relax structures at the theoretical pressures defined by the calculated stress. In the relaxed equilibrium configuration, the forces on the atoms are less than 0.006 eV/Å, and the deviation of the stress tensor from a diagonal hydrostatic form is less than 1 kbar (0.1 GPa). The application of DFT-based total-energy calculations to the study of semiconductors properties under high pressure has been reviewed in Ref. 65, showing that the phase stability, electronic, and dynamical properties of compounds under pressure are well described by DFT.

We have also performed lattice dynamics calculations of the phonons at the zone center (Γ point) of the BZ. Our theoretical results enable us to assign the Raman modes observed for the different phases. Furthermore, the calculations provide information about the symmetry of the modes and polarization vectors. Highly converged results on forces are required for the calculation of the dynamical matrix. We use the direct force constant approach.66 The construction of the dynamical matrix at the Γ point of the BZ is particularly simple and involves separate calculations of the forces in which a fixed displacement from the equilibrium configuration of the atoms within the primitive unit cell is considered. Symmetry aids by reducing the number of such independent displacements, reducing the computational effort in the study of the analyzed structures considered in this work. Diagnosticization of the dynamical matrix provides both the frequencies of the normal modes and their polarization vectors. This allows us to identify the irreducible representation and the character of the phonons modes at the Γ point.

IV. RESULTS AND DISCUSSION

Since the primitive cell of cubic In2O3 contains 8 formula units, group theory predicts that this structure should have 120 vibrational modes with the following representation:

$$\Gamma = 4A_g(R) + 4E_g(R) + 14T_g(R) + 5A_u + 5E_u + 17T_u(IR),$$

where $E$ and $T$ (also noted $F$ in the literature) modes are double and triple degenerated, respectively. The 22 gerade (g) modes are Raman-active (R) modes, 16 $T_u$ modes are infrared (IR)-active modes, the $A_u$ and $E_u$ are silent modes, and one $T_u$ mode corresponds to acoustic vibrations.

Figures 2(a) and 2(b) show unpolarized Raman spectra at room temperature in bulk and nano In2O3, respectively. Unlike previous works where a maximum of seven Raman modes (109, 135, 305, 366, 495, 513, and 629 cm$^{-1}$) have been observed,46,47,50,54 we have observed up to sixteen Raman-active modes of bulk cubic In2O3 powder at room conditions. The Raman spectrum is dominated by the stretching mode at 131 cm$^{-1}$ and by the broad mode at 306 cm$^{-1}$. Table I summarizes the zero-pressure experimental frequencies and pressure coefficients of the Raman-active modes in bulk and nano In2O3. Our frequencies at ambient pressure are in good agreement with the theoretical frequencies of the Raman-active modes obtained from our ab initio calculations and with the Raman-active modes already reported in the literature.42,46,47,50 Furthermore, thanks to our ab initio calculations we have assigned the symmetry of the different observed Raman modes [see Figs. 2(a) and 2(b)]. As regards nano In2O3, only seven modes have been clearly observed at ambient pressure. Their frequencies are rather close to those of bulk In2O3, as can be seen in Table I, since our nanoparticles have around 9 nm and phonon confinement effects are likely negligible for particles above 4 nm.67

Figures 3(a) and 3(b) show selected Raman spectra of bulk In2O3 at different pressures and the pressure dependence of the Raman mode frequencies up to 31.6 GPa, respectively. On the other hand, Figs. 4(a) and 4(b) show selected Raman spectra of nano In2O3 at different pressures and the pressure dependence of the Raman mode frequencies up to 30 GPa, respectively. When comparing Figs. 3(a) and 4(a), one can appreciate that the Raman spectra of bulk In2O3 have better quality than that of nano In2O3. In both bulk and nano In2O3, all Raman-active mode frequencies increase with pressure in a monotonous way till the maximum pressure attained in the experiment. Therefore, apparently, no
TABLE I. Experimental Raman-mode frequencies at room pressure and their pressure coefficients in bulk and nanocrystalline cubic In$_2$O$_3$. Experimental parameters have been obtained by fitting measured data to linear ($\omega = \omega_0 + \frac{\partial \omega}{\partial P}P$) or quadratic ($\omega = \omega_0 + \frac{\partial \omega}{\partial P}P + \frac{\partial^2 \omega}{\partial P^2}P^2$) expressions. Theoretical Raman-mode frequencies at room pressure and their pressure coefficients in bulk cubic In$_2$O$_3$ along with previously reported Raman-mode frequencies at room pressure are also shown for comparison.

<table>
<thead>
<tr>
<th>Mode (Sym)</th>
<th>$\omega_0$ (cm$^{-1}$)</th>
<th>$\frac{\partial \omega}{\partial P}$ (cm$^{-1}$ GPa$^{-1}$)</th>
<th>$\frac{\partial^2 \omega}{\partial P^2}$ (cm$^{-1}$ GPa$^{-2}$)</th>
<th>$\omega_0$ (cm$^{-1}$)</th>
<th>$\frac{\partial \omega}{\partial P}$ (cm$^{-1}$ GPa$^{-1}$)</th>
<th>$\frac{\partial^2 \omega}{\partial P^2}$ (cm$^{-1}$ GPa$^{-2}$)</th>
<th>$\omega_0$ (cm$^{-1}$)</th>
<th>$\frac{\partial \omega}{\partial P}$ (cm$^{-1}$ GPa$^{-1}$)</th>
<th>$\frac{\partial^2 \omega}{\partial P^2}$ (cm$^{-1}$ GPa$^{-2}$)</th>
</tr>
</thead>
<tbody>
<tr>
<td>$T_g$</td>
<td>106 (1)</td>
<td>0.01 (1)</td>
<td>-0.008 (2)</td>
<td>108 (1)</td>
<td>0.07 (3)</td>
<td>-0.006 (2)</td>
<td>109$^{50}$</td>
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<tr>
<td>$T_e$</td>
<td>114 (1)</td>
<td>0.3 (1)</td>
<td>-0.006 (2)</td>
<td>118 (1)</td>
<td>0.4 (1)</td>
<td>-0.009 (3)</td>
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<td></td>
<td></td>
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<tr>
<td>$A_g$</td>
<td>128 (1)</td>
<td>0.8 (1)</td>
<td>-0.009 (3)</td>
<td>131 (1)</td>
<td>1.0 (1)</td>
<td>-0.02 (1)</td>
<td>131$^{47,50}$</td>
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<tr>
<td>$T_e$</td>
<td>148 (1)</td>
<td>1.2 (1)</td>
<td>-0.01 (1)</td>
<td>152 (1)</td>
<td>1.4 (1)</td>
<td>-0.02 (1)</td>
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<td></td>
<td></td>
</tr>
<tr>
<td>$E_g$</td>
<td>165 (1)</td>
<td>1.1 (1)</td>
<td>-0.008 (2)</td>
<td>169 (1)</td>
<td>0.8 (1)</td>
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<td>1.8 (1)</td>
<td>-0.02 (1)</td>
<td>205 (3)</td>
<td>1.3 (1)</td>
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<tr>
<td>$T_e$</td>
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<td>1.5 (1)</td>
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<td>$T_g$</td>
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<td>2.2 (2)</td>
<td>-0.01 (1)</td>
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<td>2.4 (2)</td>
<td>-0.03 (1)</td>
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<td>2.5 (2)</td>
<td>-0.03 (1)</td>
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<tr>
<td>$A_g$</td>
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<td>-0.03 (1)</td>
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<td>4.0 (3)</td>
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<td>3.3 (2)</td>
<td>-0.02 (1)</td>
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<tr>
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<td>3.6 (3)</td>
<td>-0.02 (1)</td>
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<td>-0.02 (1)</td>
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<tr>
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<td>-0.03 (1)</td>
<td>467 (4)</td>
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<td>3.4 (3)</td>
<td>-0.02 (1)</td>
<td>495 (2)</td>
<td>3.7 (3)</td>
<td>-0.04 (1)</td>
<td>494 (3)</td>
<td>3.8 (2)</td>
<td>-0.03 (1)</td>
</tr>
<tr>
<td>$T_g$</td>
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<td>5.0 (3)</td>
<td>-0.03 (1)</td>
<td>513 (4)</td>
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<tr>
<td>$T_g$</td>
<td>520 (4)</td>
<td>4.7 (3)</td>
<td>-0.02 (1)</td>
<td>565 (4)</td>
<td>5.2 (3)</td>
<td>-0.03 (1)</td>
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<tr>
<td>$A_g$</td>
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<td>5.4 (3)</td>
<td>-0.03 (1)</td>
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<td>5.4 (3)</td>
<td>-0.03 (1)</td>
<td>628 (2)</td>
<td>6.0 (2)</td>
<td>-0.09 (3)</td>
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</tbody>
</table>

FIG. 3. (a) Selected Raman spectra of bulk In$_2$O$_3$ at different pressures up to 31.6 GPa. (b) Pressure dependence of the Raman-mode frequencies of bulk In$_2$O$_3$. Symbols correspond to experimental data. Filled (empty) black triangles up (down) correspond to upstroke (downstroke). Empty circles correspond with new peaks observed at 31.6 GPa, not related to the cubic phase. Black solid (dashed) lines represent theoretical data for observed (not observed) Raman-active modes in bulk In$_2$O$_3$. Red (blue) lines are theoretical data for Raman-active modes of the rhombohedral corundum (orthorhombic Rh$_2$O$_3$-II) phase in bulk In$_2$O$_3$.  

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phase transition seems to occur neither in bulk nor in nano In$_2$O$_3$ up to 30 GPa. Furthermore, on releasing pressure, the Raman spectrum of bulk In$_2$O$_3$ is similar to the initial one but with peaks slightly broadened. A similar Raman spectrum but with less defined features was obtained in the recovered sample of nano In$_2$O$_3$ at room pressure. It can be also observed that the peak widths of the Raman modes in the nanocrystalline sample are much larger than in the bulk leading to a possible overlapping of several Raman-active modes.

Figures 3(b) and 4(b) show the experimental pressure dependence of the first-order Raman-active mode frequencies for bulk and nano In$_2$O$_3$, respectively. These figures also include the theoretical pressure dependence of the Raman-active modes in the bulk bixbyite phase for comparison. As observed, most of the Raman modes exhibit a non-linear blue-shift with pressure, which is also in good agreement with our ab initio calculations up to the highest pressure attained in these experiments. Most of the Raman modes show a sublinear dependence of the frequency vs. pressure till 30 GPa, which is not observed when frequency is plotted vs. the relative volume variation, $\Delta V/V_0$, (not shown). This result suggests that the Gruneisen parameter of the Raman modes in cubic In$_2$O$_3$ is almost constant along the pressure range between ambient pressure and 30 GPa. Therefore, this means that there is no change in the force of the bondings what suggests that there is no charge redistribution between In and O atoms up to 30 GPa. Additionally, it can be appreciated that all the calculated frequencies are slightly underestimated due to the underestimation of the cohesion energy in the GGA approximation. The underestimation of experimental frequencies by GGA calculations is less than 5%; therefore, higher frequencies show larger experimental-theoretical differences than lower frequencies. On the basis of the comparison of our experimental and theoretical frequencies, we propose that the peaks of the Raman-active modes centred at 395.8 and 589.7 cm$^{-1}$ should have $E_g$ symmetry [see Fig. 2(a)]. Similarly, the symmetry proposed for the Raman-active mode in In$_2$O$_3$ nanocrystals centred at 591.1 cm$^{-1}$ is also $E_g$ [see Fig. 2(b)].

An interesting feature of the Raman spectra of bulk In$_2$O$_3$ is the splitting of the broad peak near 306 cm$^{-1}$ into two peaks, observed for pressures above 1.5 GPa. The broadening of this peak is evident in the Raman spectrum at 3.9 GPa [see Fig. 3(a)]. According to our calculations up to four Raman-active modes should appear in the region near 300 cm$^{-1}$ for the cubic phase of In$_2$O$_3$. Note that out of the four predicted Raman modes in this region, three have similar pressure coefficients while the lowest in frequency has a smaller pressure coefficient (see Fig. 3(b) and Table I). Therefore, we ascribe the splitting observed above 1.5 GPa to two Raman-active modes of the cubic phase almost degenerate in frequency at room pressure that have very different pressure coefficients. In bulk In$_2$O$_3$ [Fig. 4(b)], the splitting of the broad peak at 306 cm$^{-1}$ was observed above 4 GPa; i.e., later than for bulk In$_2$O$_3$. A possible explanation for this behavior could be the larger overlapping of the two modes near 306 cm$^{-1}$ in nanocrystals compared to the bulk, which prevents the observation of this splitting at smaller pressures.

In a previous work, Liu et al. observed the splitting of the modes near 306 cm$^{-1}$ above 12.2 GPa and attributed it to the onset of a phase transition from the cubic bixbyite-type to the rhombohedral corundum-type structure. With this interpretation, their high-pressure Raman scattering data matched with the observation of a new XRD peak above 15.3 GPa that they attributed to the rhombohedral phase. Furthermore, both experimental results seemed to agree with prior theoretical predictions that considered that a cubic-to-rhombohedral phase transition could be observed in In$_2$O$_3$ above 3.8 GPa. Curiously, the observation of the cubic-to-

![Image](image_url)
rhombohedral phase transition was also claimed in a recent paper both on bulk and 6-nm-size nanocrystals. However, our theoretical calculations do not predict the cubic-to-rhombohedral phase transition up to around 15 GPa in good agreement with previous calculations of Gurlo et al. Furthermore, in agreement with Gurlo et al., we have found that our calculations predict the cubic-to-orthorhombic Rb₂O₂·II phase transition to occur at pressures even lower than those for the cubic-to-rhombohedral transition; however, no report for the cubic-to-orthorhombic pressure-induced phase transition has been claimed at room temperature to our knowledge. Therefore, we consider that the splitting of the two Raman modes near 306 cm⁻¹ as pressure increases does not constitute an evidence of the phase transition of In₂O₃ from the cubic-to-rhombohedral phase transition since this splitting is expected for two degenerate modes of the cubic phase at ambient pressure according to our ab initio calculations.

A curious feature of the Raman spectra of bulk In₂O₃ at different pressures is that, despite there is a general decrease of intensity of the Raman modes with increasing pressure, there is an increase of the relative peak intensity of the peak of intensity of the Raman modes with increasing pressure, different pressures is that, despite there is a general decrease in intensity or even disappear at low pressures. It can be noted that a broad band appears as a shoulder in the low-frequency side of the 495 cm⁻¹ peak above 9.4 GPa. In fact, similar broad bands, but less clearly observed, are also developed above 9.4 GPa in the low-frequency side of the peaks at 306 and 365 cm⁻¹. Similar broad bands were already reported by Liu et al. above 12.8 GPa and were attributed to the onset of a phase transition to the rhombohedral phase with some disorder, as it was previously observed in corundum-type Ga₂O₃. However, we must highlight that these bands do not correspond to Raman-active modes predicted by our theoretical calculations neither for the cubic phase nor for the rhombohedral or orthorhombic phases. Furthermore, we must note that neither our Raman spectra nor those obtained by Liu et al. above 15 GPa resemble to those measured for the rhombohedral phase of In₂O₃ at ambient pressure. Therefore, on the basis of our Raman scattering measurements, our lattice dynamics calculations and the experimental evidence of Raman modes of the rhombohedral phase at ambient conditions, we cannot confirm either the cubic-to-rhombohedral or the cubic-to-orthorhombic phase transitions below 30 GPa but just the existence of some features that suggest the onset of a phase transition to an unknown structure.

Taking into account ab initio calculations, one could explain the observation of two XRD peaks near 6.4° and 9° above 15 GPa in both bulk and nanocrystals and the absence of new Raman modes around that pressure by invoking that they are signs of the onset of a phase transition to the rhombohedral phase. However, a rather high kinetic barrier occurs for the cubic-to-rhombohedral or cubic-to-orthorhombic phase transitions. In fact, data of previous authors show that the phase transition is far from complete even at 30 GPa. In this sense, high kinetic barriers would allow the cubic phase being present at least till 30 GPa. Additionally, if the polarizability of the corundum phase is smaller than that of the cubic phase, the Raman scattering of the corundum phase could be of smaller intensity than that of the cubic phase and this would explain the absence of Raman-active modes of the corundum phase above 15 GPa while XRD peaks of the high-pressure phase are observed above that pressure.

Finally, we have to mention that several new Raman peaks are observed in the spectrum of bulk In₂O₃ at 31.6 GPa whose frequencies are plotted in Fig. 3(b) with open circles. These peaks are too weak to be clearly identified with any possible high-pressure phase; however, they indicate that, as far as Raman scattering concerns, the phase transition seems to take place above 30 GPa. We need to reach higher pressures to shed more light on the nature of the pressure-induced phase transitions in In₂O₃ at room temperature.

V. CONCLUSIONS

We report an accurate Raman spectrum at room conditions of bulk cubic In₂O₃, showing up to sixteen Raman-active modes. Thanks to ab initio calculations we have been able to assign the symmetry of most of the observed Raman-active modes in bulk and nanocrystalline cubic In₂O₃. We have also reported the pressure dependence of the Raman-active mode frequencies of the cubic phase in both bulk and nanocrystalline In₂O₃ up to 31.6 and 30 GPa, respectively. The pressure dependence of the experimental Raman modes shows a considerable non-linear pressure dependence that matches with the theoretical predictions. We have found no clear sign of a phase transition to the rhombohedral corundum-type structure neither in the bulk nor in the nanocrystals of cubic In₂O₃ till 30 GPa. Instead, we have found a considerable broadening of some Raman modes above 15 GPa that could be indicative of the onset of a phase transition. New modes appear in the Raman spectrum of bulk In₂O₃ above 30 GPa that seem to indicate that the phase transition occurs above this pressure in this compound at room temperature.

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